Vishay Semiconductors

# High Performance Schottky Rectifier, 100 A



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PowerTab<sup>®</sup>

PRODUCT SUMMARY				
Package	PowerTab <sup>®</sup>			
I <sub>F(AV)</sub>	100 A			
V <sub>R</sub>	30 V			
$V_F$ at $I_F$	0.56 V			
I <sub>RM</sub>	460 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	9 mJ			

### FEATURES

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
  COMPLIANT
- Screw mounting only
- AEC-Q101 qualified
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-100BGQ030HF4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS				
I=	Rectangular waveform	100	А			
I <sub>F(AV)</sub>	T <sub>C</sub>	106	°C			
V <sub>RRM</sub>		30	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	4500	А			
100 A <sub>pk</sub> (typical)		0.49	V			
V <sub>F</sub>	TJ	150	°C			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-100BGQ030HF4	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	30	N/		
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS			
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 106 °C	100	А		
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	4500	A	
		10 ms sine or 6 ms rect. pulse		850		
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 8 \text{ A}, L = 1.12 \text{ mH}$ 3		36	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		А		

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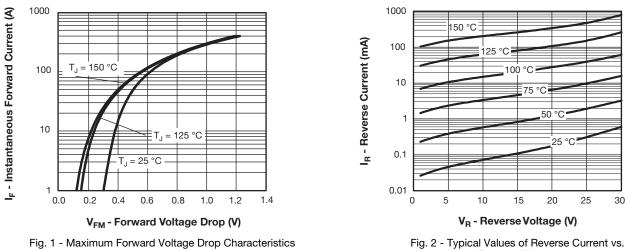
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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS
		50 A	T <sub>.1</sub> = 25 °C	0.47	0.5	V
Forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	100 A	1j=23 0	0.56	0.63	
Forward voltage drop	VFM (")	50 A	T = 150 °C	0.36	0.4	
		100 A	T <sub>J</sub> = 150 °C	0.49	0.56	
		T <sub>J</sub> = 125 °C, V <sub>R</sub> = 15 V		80	160	
	I (1)	$T_{J} = 150 \text{ °C}, V_{R} = 30 \text{ V}$		800	1100	
Reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		0.6	2.4	- mA
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	260	460	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal range 100 kHz to 1 MHz) 25 °C 3800			00	pF
Typical series inductance	Ls	Measured from tab to mounting plane 3.5 nl			nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µ:			V/µs	

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MEG	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and temperature range	storage	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resis junction to case	tance,	R <sub>thJC</sub>	DC operation	0.50	°C/W	
Typical thermal resistar case to heatsink	nce,	R <sub>thCS</sub> Mounting surface, smooth and greased		0.30	0,11	
Approvimate weight				5	g	
Approximate weight				0.18	oz.	
Mounting torque	minimum			1.2 (10)	N · m	
Mounting torque	maximum			2.4 (20)	(lbf $\cdot$ in)	
Marking device	Marking device Case style PowerTab <sup>®</sup> 100BGQ030		Q030H			



**Reverse Voltage** 

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## VS-100BGQ030HF4

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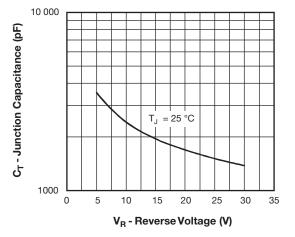


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

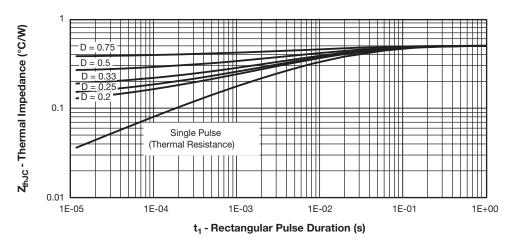
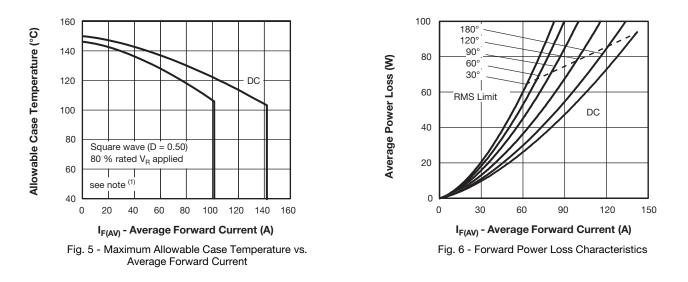


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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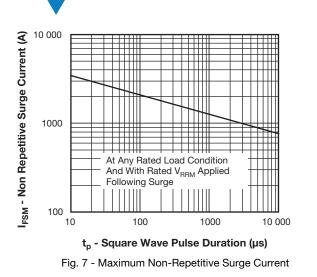
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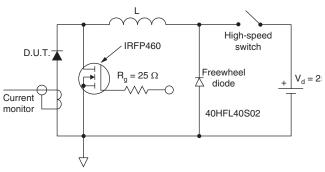
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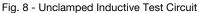
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### Note

 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \ x \ V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd\_{REV} = Inverse power loss =  $V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = 80 \ \%$  rated  $V_R$ 

### **ORDERING INFORMATION TABLE**

Device code	VS-	100	BGQ	030	н	F4	
	1	2	3	4	5	6	Ι
	1 · 2 ·		hay Serr rrent rati				
	3		sential pa	0 (		•)	
	4	- Vol	tage rati	ng (030	= 30 V)		
	5 -	. н=	AEC-Q	101 qua	lified		
	6	- Env	/ironmer	ntal digit	:		
	-	- F4	= RoHS	complia	int and t	otally le	ad (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	EFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-100BGQ030HF4	25	375	Antistatic plastic tube			

#### LINKS TO RELATED DOCUMENTS

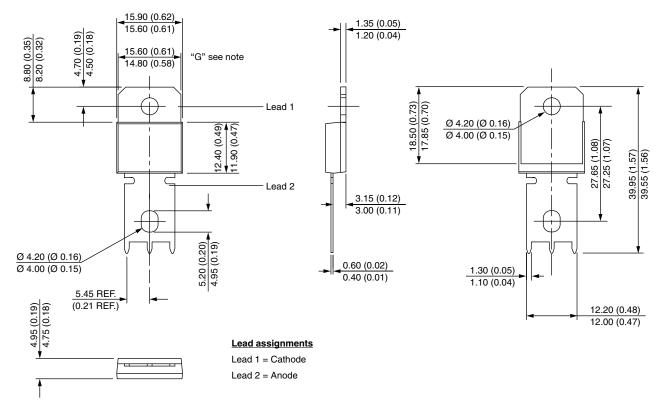
Dimensions	www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95467				
Application note	www.vishay.com/doc?95179				



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### **DIMENSIONS** in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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